

Metal Composite Power Inductor (Thin Film) Specification Sheet



CIGT201608LMR68MNE (2016 / EIA 0806)

APPLICATION

Smart phones, Tablet, Wearable devices, Power converter modules, etc.

FFATURES

Small power inductor for mobile devices
Low DCR structure and high efficiency inductor for power circuits.
Monolithic structure for high reliability
Free of all RoHS-regulated substances
Halogen free

RECOMMENDED LAND PATTERN



Unit : mm
2016
0.8
0.8
1.8

DIMENSION



TYPE	Dimension [mm]							Dimension [mm]					
IIFL	L	W	T	D									
2016	2.0±0.2	1.6±0.2	0.8 max	0.5±0.2									

DESCRIPTION

Part no.	Size Thickness [mm] (max)	Thickness	Inductance	Inductance tolerance	DC Resist	ance [mΩ]	Rated DC Cu	rrent (Isat) [A]	Rated DC C	,
		[uH]	(%)	Max.	Тур.	Max.	Тур.	Max.	Тур.	
CIGT201608LMR68MNE	0806/2016	0.8	0.68	±20	53	46	3.3	3.6	2.7	2.9

- * Inductance : Measured with a LCR meter 4991A(Agilent) or equivalent (Test Freq. 1MHz, Level 0.1V)
- * DC Resistance : Measured with a Resistance HI-TESTER 3541(HIOKI) or equivalent
- * Maximum allowable DC current : Value defined when DC current flows and the initial value of inductance has decreased by 30% or when current flows and temperature has risen to 40 °C whichever is smaller. (Reference: ambient temperature is 25 °C±10)

(Isat): Allowable current in DC saturation: The DC saturation allowable current value is specified when the decrease of

(Irms) : Allowable current of temperature rise : The temperature rise allowable current value is specified when temperature of the inductor is raised 40 ℃ by DC current. (Reference: ambient temperature is 25 ℃±10)

- * Absolute maximum voltage : Absolute maximum voltage DC 20V.
- * Operating temperature range : -40 to +125 $^{\circ}\text{C}$ (Including self-temperature rise)

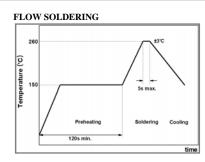
PRODUCT IDENTIFICATION

<u>CIG</u>	<u>T</u>	<u> 2016</u>	<u>80</u>	<u>LM</u>	<u>R68</u>	<u>M</u>	<u>N</u>	<u>E</u>
(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)

- (1) Power Inductor
- (3) Dimensior (2016: 2.0mm ×1.6 mm)
- (5) Remark (Characterization Code)
- (7) Toleranc (M:±20%)
- (8) Internal Code
- (9) Packaging (C:paper tape, E:embossed tape)
- (2) Type (T: Metal Composite Thin Film Type)
- (4) Thicknes (08: 0.8mm)
- (6) Inductan (R68: 0.68 uH)

RECOMMENDED SOLDERING CONDITION

REFLOW SOLDERING 260 230 100 max. Preheating Soldering Cooling 30 - 60s time



RON SOLDERING	
Temperature of Soldering Iron Tip	280 ℃ max.
Preheating Temperature	150℃min.
Temperature Differential	ΔT≤130 °C
Soldering Time	3sec max.
Wattage	50W max.

PACKAGING

Packaging Style	Quantity(pcs/reel)
Embossed Taping	3000 pcs

Item	Specified Value	Т	est Condition	
Solderability	More than 90% of terminal electrode should be soldered newly.	•	for 4±1 seconds, and preheated at the specimen shall be immersed in seconds.	
Resistance to Soldering	No mechanical damage. Remaining terminal Electrode: 75% min. Inductance change to be within ±20% to the initial.	•	for 4±1 seconds, and preheated at the specimen shall be immersed in ±0.5 seconds.	
Thermal Shock (Temperature Cycle test)	No mechanical damage Inductance change to be within ±20% to the initial.	Repeat 100 cycles under -40±3°C for 30 min → 85±		
High Temp. Humidity Resistance Test	No mechanical damage Inductance change to be within ±20% to the initial	85±2°C, 85%RH, for 500± Measure the test items af and humidity for 24 hours	ter leaving at normal temperature	
Low Temperature Test	No mechanical damage Inductance change to be within ±20% to the initial.	Solder the sample on PCI at -55±2°C for 500±12 hor Measure the test items af and humidity for 24hours.	urs. ter leaving at normal temperature	
High Temperature Test	No mechanical damage Inductance change to be within ±20% to the initial.	hours.	B. Exposure at 125±2°C for 500±12 ter leaving at normal temperature	
High Temp. Humidity Resistance Loading Test	No mechanical damage Inductance change to be within ±20% to the initial	85±2°C, 85%RH, Rated C Measure the test items af and humidity for 24 hours	ter leaving at normal temperature	
High Temperature Loading Test	No mechanical damage Inductance change to be within ±20% to the initial	85±2°C, Rated Current for 500±12 hours. Measure the test items after leaving at normal temperature and humidity for 24 hours.		
Reflow Test	No mechanical damage Inductance change to be within ±20% to the initial	Peak 260±5℃, 3 times		
Vibration Test	No mechanical damage Inductance change to be within ±20% to the initial.	Solder the sample on PCB. Vibrate as apply 10~55Hz, 1.5mm amplitude for 2 hours in each of three(X,Y,Z) axis (total 6 hours).		
	No mechanical damage	Bending Limit; 2mm Test Speed; 1.0mm/sec. Keep the test board at the PCB thickness: 1.6mm	e limit point in 5 sec.	
Bending Test	19,00	20 R340	Unit:mm	
	46	45	_	
	No indication of peeling shall occur on the	W(kgf)	TIME(sec)	
	terminal electrode.	0.5	10±1	
Terminal Adhesion Test		w		
Drop Test	No mechanical damage Inductance change to be within ±20% to the initial.	Random Free Fall test on concrete plate. 1 meter, 10 drops		
Ipeak (AC+DC Load Life)	No mechanical damage Inductance change to be within ±20% to the initial	85±2°C, 85%RH, Load(Ipeak) for 120 hours. (Frequncy:1MHz, Load(Ipeak):1.5hr on / 0.5hr off) Measure the test items after leaving at normal temperature and humidity for 24 hours. * Load(Ipeak) = Irms(max)×1.4		



Metal Composite Power Inductor (Thin Film) Data Sheet

2. Description

1. Model: CIGT201608LMR68MNE

Part no.	Size	Thickness	Inductance	e Inductance tolerance	DC Resist	ance [mΩ]	Rated DC Cu	rrent (Isat) [A]	Rated DC C	,
	[inch/mm]	[mm] (max)	[uH]	(%)	Max.	Тур.	Max.	Тур.	Max.	Тур.
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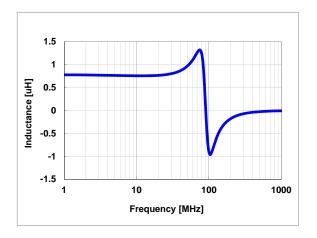
(Isat): Allowable current in DC saturation: The DC saturation allowable current value is specified when the decrease of the initial inductance value at 30% (Reference: ambient temperature is 25 °C±10)

(Irms) : Allowable current of temperature rise : The temperature rise allowable current value is specified when temperature of the inductor is raised 40 ℃ by DC current. (Reference: ambient temperature is 25 ℃±10)

3. Characteristics data

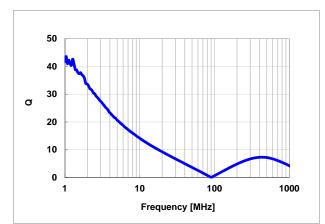
1) Frequency characteristics (Ls)

Agilent E4294A +E4991A , 1MHz to 1,000MHz

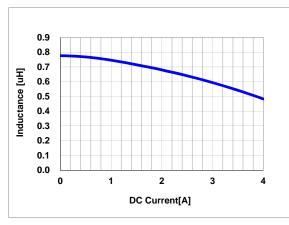


2) Frequency characteristics (Q)

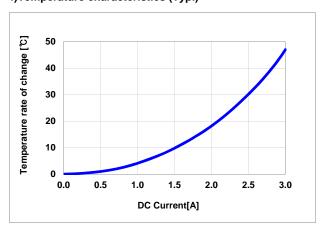
Agilent E4294A +E4991A , 1MHz to 1,000MHz



3) DC Bias characteristics (Typ.)



4)Temperature characteristics (Typ.)





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^{*} Maximum allowable DC current : Value defined when DC current flows and the initial value of inductance has decreased by 30% or when current flows and temperature has risen to 40 °C whichever is smaller. (Reference: ambient temperature is 25 °C±10)

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